



# VOIDLESS HERMETICALLY SEALED SWITCHING DIODES

Qualified per MIL-PRF-19500/578

## DESCRIPTION

This popular surface mount equivalent JEDEC registered switching/signal diodes are military qualified and available with internal metallurgical bonded construction. These small low capacitance diodes with very fast switching speeds are hermetically sealed and bonded into a "D-5D" package. They may be used in a variety of fast switching applications including computers and peripheral equipment such as magnetic cores, thin-film memories, plated-wire memories, as well as decoding or encoding applications, etc. Microsemi also offers a variety of other switching/signal diodes.

Important: For the latest information, visit our website http://www.microsemi.com.

#### **FEATURES**

- JEDEC registered surface mount equivalents of 1N6638, 1N6642, and 1N6643.
- Ultra fast recovery time.
- Very low capacitance.
- Metallurgically bonded.
- Non-cavity glass package.
- JAN, JANTX, JANTXV and JANS qualifications are available per MIL-PRF-19500/578.
- Replacements for 1N4148UR, 1N4148UR-1, 1N4150UR-1, and 1N914UR.
- RoHS compliant devices available (commercial grade only).

### **APPLICATIONS / BENEFITS**

• Small size for high density mounting (see package illustration).

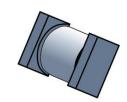
Ideal for: High frequency data lines RS-232 & RS–422 Interface Networks Ethernet: 10 Base T Switching core drivers LAN

Computers

#### MAXIMUM RATINGS @ T<sub>A</sub> = +25 °C unless otherwise noted

Parameters/Test Conditions	Symbol	Value	Unit	
Junction and Storage Temp	$T_{\rm J}$ and $T_{\rm STG}$	-65 to +175	°C	
Thermal Resistance Junction-to-End	R <sub>ØJEC</sub>	40	°C/W	
Thermal Resistance Junction-to-Amb	R <sub>eja</sub>	250	°C/W	
Peak Forward Surge Current @ T <sub>A</sub> =	I <sub>FSM</sub>	2.5	А	
(Test pulse = 8.3 ms, half-sine wave.)				
Average Rectified Forward Current @	lo	300	mA	
(Derate at 4.6 mA/°C Above $T_{EC}$ = +				
Breakdown Voltage: 1N6638US		V <sub>BR</sub>	150	V
	1N6642US		100	
	1N6643US		75	
Working Peak Reverse Voltage:	1N6638US	V <sub>RWM</sub>	125	V
	1N6642US		75	
	1N6643US		50	

**NOTES:** 1.  $T_A = +75$  °C on printed circuit board (PCB), PCB = FR4 - .0625 inch (1.59 mm) 1-layer 1-Oz Cu, horizontal, in still air; pads for US = .061 inch (1.55 mm) x .105 inch (2.67 mm);  $R_{\Theta JA}$  with a defined PCB thermal resistance condition included, is measured at  $I_0 = 300$  mA. <u>Qualified Levels</u>: JAN, JANTX, JANTXV and JANS



## "D" SQ-MELF (D-5D) Package

Also available in:

"D" Package (axial-leaded) 1N6638 42 43

MSC – Lawrence

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 Tel: (978) 620-2600 Fax: (978) 689-0803

MSC – Ireland

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

Website:

www.microsemi.com





## **MECHANICAL and PACKAGING**

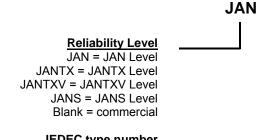
- CASE: Voidless hermetically sealed hard glass.
- TERMINALS: Tin-Lead plate with >3% Lead. Solder dip is available upon request.
- MARKING: Body painted and alpha numeric.
- POLARITY: Cathode indicated by band.
- Tape & Reel option: Standard per EIA-481-1-A with 12 mm tape. Consult factory for quantities.
- See <u>Package Dimensions</u> on last page.

### PART NOMENCLATURE

US

(e3)

1N6638



RoHS Compliance e3 = RoHS compliant (<u>available</u> on commercial grade only) Blank = non-RoHS compliant

Surface Mount Package

JEDEC type number

See Electrical Characteristics table

	SYMBOLS & DEFINITIONS						
Symbol	Definition						
V <sub>BR</sub>	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.						
V <sub>RWM</sub> Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.							
VF	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.						
I <sub>R</sub>	Maximum Reverse Current: The maximum reverse (leakage) current that will flow at the specified voltage and temperature.						
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage.						
t <sub>rr</sub>	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified recovery decay point after a peak reverse current is reached.						

#### ELECTRICAL CHARACTERISTICS @ 25°C unless otherwise noted.

TYPE NUMBER	MAXIMUM FORWARD VOLTAGE V <sub>F</sub> @ ↓ R			MAXIMUM DC REVERSE CURRENT			REVERSE RECOVERY TIME t <sub>rr</sub> (Note 1)	MAXIMUM FORWARD RECOVERY VOLTAGE AND TIME I <sub>F</sub> =200mA, t <sub>r</sub> =1ns		MAXIMUM JUNCTION CAPACITANCE f = 1 MHz Vsig = 50 mV (p-p)	
			I <sub>R1</sub> V <sub>R</sub> = 20 V	I <sub>R2</sub> V <sub>R</sub> =V <sub>RWM</sub>	I <sub>R3</sub> V <sub>R</sub> =20 V T <sub>A</sub> = +150 °C	I <sub>R4</sub> V <sub>R</sub> =V <sub>RWM</sub> T <sub>A</sub> = +150 °C		V <sub>FRM</sub>	t <sub>fr</sub>	V <sub>R</sub> =0 V	V <sub>R</sub> =1.5 V
	V @ mA	V @ mA	nA	nA	μA	μA	ns	v	ns	pf	pf
1N6638US	0.8 V @ 10 mA	1.1 V @ 200 mA	35	500	50	100	4.5	5.0	20	2.5	2.0
1N6642US	0.8 V @ 10 mA	1.2 V @ 100 mA	25	500	50	100	5.0	5.0	20	5.0	2.8
1N6643US	0.8 V @ 10 mA	1.2 V @ 100 mA	50	500	75	100	6.0	5.0	20	5.0	2.8

NOTE: 1. Reverse Recovery Time Test Conditions – I<sub>F</sub>=I<sub>R</sub>=10 mA, I<sub>R(REC)</sub> = 1.0 mA, C=3 pF, R<sub>L</sub> = 100 ohms.



GRAPHS

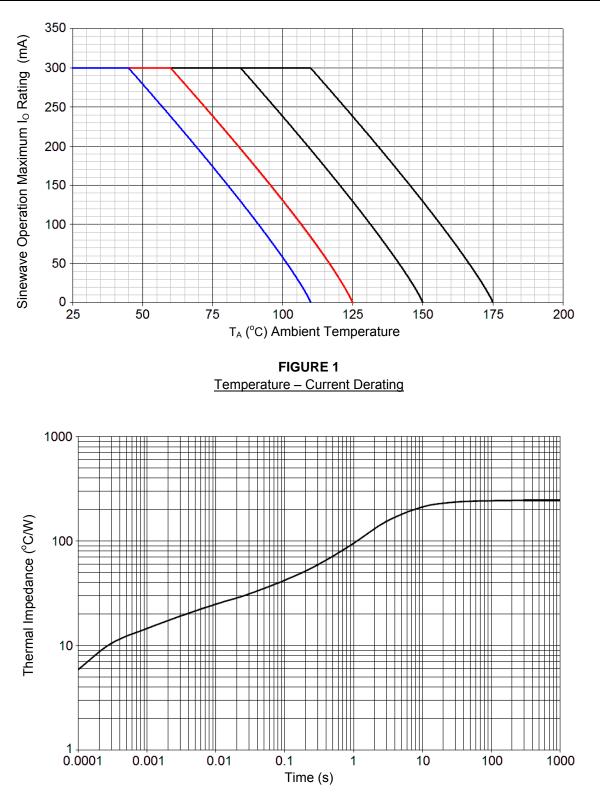


FIGURE 2 Maximum Thermal Impedance at  $T_A = 55 \ ^{\circ}C$ 

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**GRAPHS** (continued)

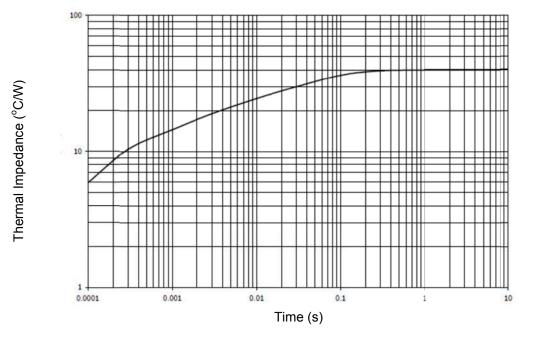


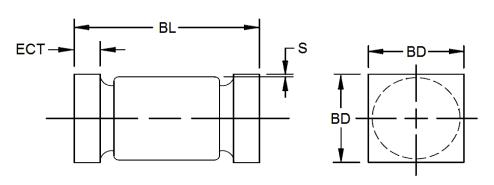
FIGURE 3 Maximum Thermal Impedance at T<sub>EC</sub> = 25 °C



# 1N6638US, 1N6642US, 1N6643US

#### PACKAGE DIMENSIONS





	IN	СН	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
BD	0.070	0.085	1.78	2.16		
ECT	0.019	0.028	0.48	0.71		
BL	0.165	0.195	4.19	4.95		
S	0.003	3 MIN.	0.08 MIN.			

#### NOTES:

- 1. Dimensions are in inches. Millimeters are given for general information only.
- 2. Dimensions are pre-solder dip.
- 3. U-suffix parts are structurally identical to the US-suffix parts.
- 4. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.